AMENDMENTS TO THE CLAIMS

This listing of claims will replace all prior versions and listings of claims in the application:

LISTING OF CLAIMS:

1. (original): A surface plasmon resonance measuring chip for use in a surface plasmon resonance measurement apparatus constituted of a light source for emitting a light beam; an optical system for making said light beam enter a dielectric block at various angles of incidence so that a condition for total internal reflection is satisfied at an interface between said dielectric block and said metal film; and photodetection means for detecting the intensity of said light beam satisfying total internal reflection at said interface to detect surface plasmon resonance; comprising:

a dielectric block;

a metal film, formed on a surface of said dielectric block, for placing a sample thereon; wherein said dielectric block is formed as a single block that includes an entrance surface which said light beam enters, an exit surface from which said light beam emerges, and a surface on which said metal film is formed;

said metal film is united with said dielectric block; and

said dielectric block is formed from a synthetic resin in which, when said light beam is p-polarized outside said dielectric block and then strikes said interface, the intensity of an s-polarized component at said interface is 50% or less of the intensity of said light beam at said interface.

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2. (original): The surface plasmon resonance measuring chip as set forth in claim 1, wherein said dielectric block is formed from a synthetic resin in which, when said light beam is p-polarized outside said dielectric block and then strikes said interface, the intensity of a s-polarized component at said interface is 30% or less of the intensity of said light beam at said interface.

- 3. (original): The surface plasmon resonance measuring chip as set forth in claim 1, wherein said dielectric block is formed from a synthetic resin in which, when said light beam is p-polarized outside said dielectric block and then strikes said interface, the intensity of a s-polarized component at said interface is 10% or less of the intensity of said light beam at said interface.
- 4. (original): The surface plasmon resonance measuring chip as set forth in claim 1, wherein said synthetic resin is a synthetic resin that is selected from polymethylmethacrylate, a cycloolefin polymer, or a cycloolefin copolymer.
- 5. (original): The surface plasmon resonance measuring chip as set forth in claim 2, wherein said synthetic resin is a synthetic resin that is selected from polymethylmethacrylate, a cycloolefin polymer, or a cycloolefin copolymer.
- 6. (original): The surface plasmon resonance measuring chip as set forth in claim 3, wherein said synthetic resin is a synthetic resin that is selected from polymethylmethacrylate, a cycloolefin polymer, or a cycloolefin copolymer.
- 7. (original): The surface plasmon resonance measuring chip as set forth in claim 1, wherein a sensing medium that exhibits a coupling reaction with a specific substance in said sample is fixed on said metal film.

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8. (original): The surface plasmon resonance measuring chip as set forth in claim 2, wherein a sensing medium that exhibits a coupling reaction with a specific substance in said sample is fixed on said metal film.

- 9. (original): The surface plasmon resonance measuring chip as set forth in claim 3, wherein a sensing medium that exhibits a coupling reaction with a specific substance in said sample is fixed on said metal film.
- 10. (currently amended): The surface plasmon resonance measuring chip as set forth in claim [[3]] 4, wherein a sensing medium that exhibits a coupling reaction with a specific substance in said sample is fixed on said metal film.
- 11. (original): The surface plasmon resonance measuring chip as set forth in claim 4, wherein a sensing medium that exhibits a coupling reaction with a specific substance in said sample is fixed on said metal film.
- 12. (original): The surface plasmon resonance measuring chip as set forth in claim 6, wherein a sensing medium that exhibits a coupling reaction with a specific substance in said sample is fixed on said metal film.
 - 13. (canceled).
- 14. (previously presented): The surface plasmon resonance measuring chip as set forth in claim 1, wherein said sample is fixed on said metal film and is held in a sample holding frame which is integrally formed on said dielectric block.
- 15. (previously presented): The surface plasmon resonance measuring chip as set forth in claim 1, wherein a top surface of said dielectric block is contiguous to said metal film

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such that there is substantially no air gap between said top surface of said dielectric block and said metal film.

- 16. (previously presented): The surface plasmon resonance measuring chip as set forth in claim 1, wherein said dielectric block and said metal film are integrally formed.
- 17. (previously presented): The surface plasmon resonance measuring chip as set forth in claim 1, wherein said dielectric block is formed in the shape of a rectangular parallelepiped.
- 18. (previously presented): The surface plasmon resonance measuring chip as set forth in claim 1, wherein said metal film comprises a vapor-deposited film.
- 19. (previously presented): The surface plasmon resonance measuring chip as set forth in claim 1, wherein said entrance surface is formed on a first portion of a spherical surface of said dielectric block and,

wherein said exit surface is formed on a second portion of said spherical surface of said dielectric block.

- 20. (previously presented): The surface plasmon resonance measuring chip as set forth in claim 1, wherein said dielectric block has a cut out portion in a region where said light beam does not penetrate.
 - 21. (previously presented): The surface plasmon resonance measuring chip as set forth in claim 1,

wherein said dielectric block is formed in a quadrangular pyramid shape, and

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wherein said dielectric block comprises a sample holding hole having a circular cross section which gradually increases in diameter toward a top surface of said dielectric block, and

wherein a bottom surface of said dielectric block is contiguous to said metal film.